

Trans GP BJT PNP 400V 8A

Manufacturers	ON Semiconductor, LLC
Package/Case	TO-220
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for MJE5852 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

MJE5852 is a bipolar junction transistor (BJT) that is commonly used in power amplifier circuits. Here are some of its features:

Features

Collector-Emitter Voltage: 60V

Collector-Base Voltage: 60V

Emitter-Base Voltage: 5V

Collector Current: 8A

DC Current Gain: 25-100

Power Dissipation: 75W

Package Type: TO-220

Application

TIP142

TIP142G

2N6045G

TIP142T

BDW93C

BDW93CG

BDW93D

BDW93DG

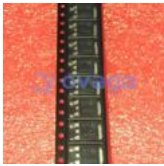


Related Products



[MJE172](#)

ON Semiconductor, LLC
TO-126



[MJD42CT4G](#)

ON Semiconductor, LLC
SOT25



[MJL21195G](#)

ON Semiconductor, LLC
TO-3PL



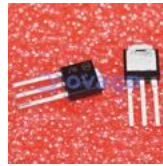
[MJ4502G](#)

ON Semiconductor, LLC
TO-204-2 (TO-3)



[MJE350G](#)

ON Semiconductor, LLC
TO-126



[MJD44H11-1G](#)

ON Semiconductor, LLC
TO-251



[MJ802G](#)

ON Semiconductor, LLC
TO-204-2



[MJH6287](#)

ON Semiconductor, LLC
TO-247